Bipolar Transistor

(-)50 V, (-)5 A, Low V_{CE(sat)}, (PNP)NPN Single TP/TP-FA

2SB1203/2SD1803

Features

- Low Collector-to-Emitter Saturation Voltage
- Excellent Linearity of h_{FE}
- Small and Slim Package Making It Easy to Make 2SB1203/2SD1803–Applied Sets Smaller

ABSOLUTE MAXIMUM RATINGS (at Ta = 25°C)

- High Current and High f_T
- Fast Switching Speed

Applications

• Relay Drivers, High–Speed Inverters, Converters, and Other General High–Current Switching Applications

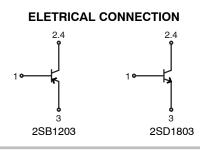
Symbol	Parameter	Condition	Rating	Unit
V _{CBO}	Collector-to-Base Voltage		(–)60	V
V _{CEO}	Collector-to-Emitter Voltage		(–)50	V
V _{EBO}	Emitter-to-Base Voltage		(–)6	V
I _C	Collector Current		(–)5	А
I _{CP}	Collector Current (Pulse)		(–)8	А
P _C	Collector Dissipation		1	W
		$Tc = 25^{\circ}C$	20	W
Tj	Junction Temperature		150	°C
Tstg	Storage Temperature		–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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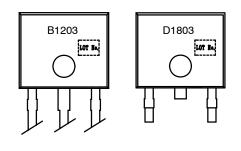




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MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

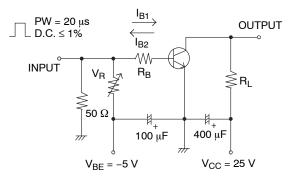
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	Collector Cutoff Current	$V_{CB} = (-)40 \text{ V}, \text{ I}_{\text{E}} = 0 \text{ A}$			(–)1	μA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = (-)4 V$, $I_{C} = 0 A$			(–)1	μA
h _{FE} 1	DC Current Gain	V_{CE} = (-)2 V, I _C = (-)0.5 A	70 (Note 1)		400 (Note 1)	
h _{FE} 2		V_{CE} = (-)2 V, I _C = (-)4 A	35			
f _T	Gain-Bandwidth Product	V_{CE} = (–)5 V, I _C = (–)1 A		(130)180		MHz
Cob	Output Capacitance	V _{CB} = (-)10 V, f = 1 MHz		(60)40		pF
V _{CE(sat})	Collector-to-Emitter Saturation Voltage	$I_{C} = (-)3 \text{ A}, I_{B} = (-)0.15 \text{ A}$		(-280)220	(-550)400	mV
V _{BE(sat)}	Base-to-Emitter Saturation Voltage	I _C = (-)3 A, I _B = (-)0.15 A		(–)0.95	(-)1.3	V
V _{(BR)CBO}	Collector-to-Base Breakdown Voltage	I _C = (-)10 μA, I _E = 0 A	(–)60			V
V _{(BR)CEO}	Collector-to-Emitter Breakdown Voltage	I_C = (-)1 mA, R_{BE} = ∞	(–)50			V
V _{(BR)EBO}	Emitter-to-Base Breakdown Voltage	$I_{E} = (-)10 \ \mu A, \ I_{C} = 0 \ A$	(–)6			V
t _{on}	Turn–On Time	See Specified Test Circuit		(50)50		ns
t _{stg}	Storage Time			(450)500		ns
t _f	Fall Time			(20)20		ns

ELECTRICAL CHARACTERISTICS (at $T_A = 25^{\circ}C$)

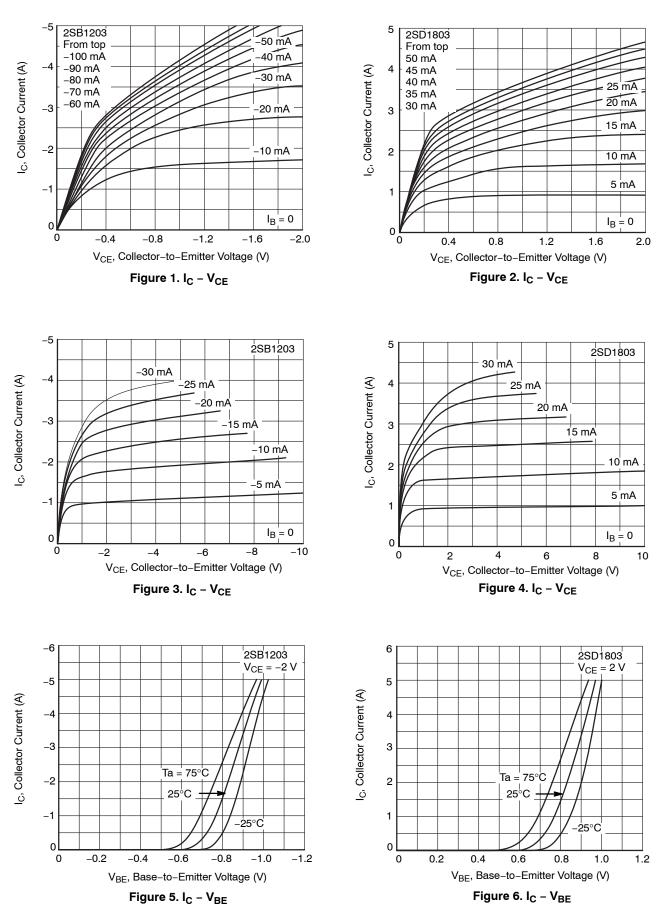
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
1. The 2SB1203/2SD1803 are classified by 0.5 A h_{FE} as follows:

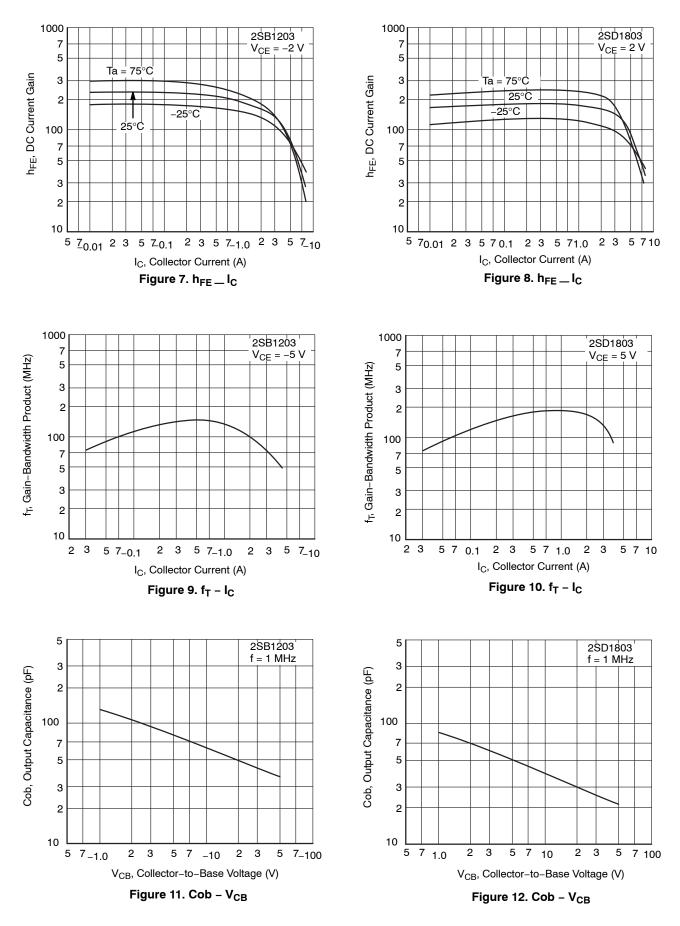
Rank	Q	R	S	Т
h _{FE}	70 to 140	100 to 200	140 to 280	200 to 400

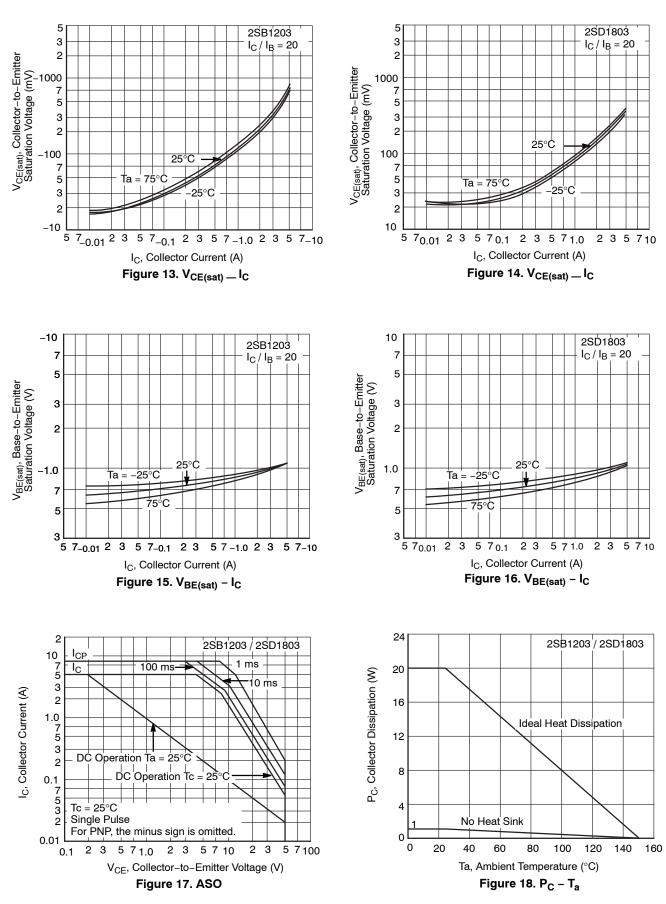
Switching Time Test Circuit



 I_C = 10 I_{B1} = –10 I_{B2} = 2 A For PNP, the polarity is reversed.







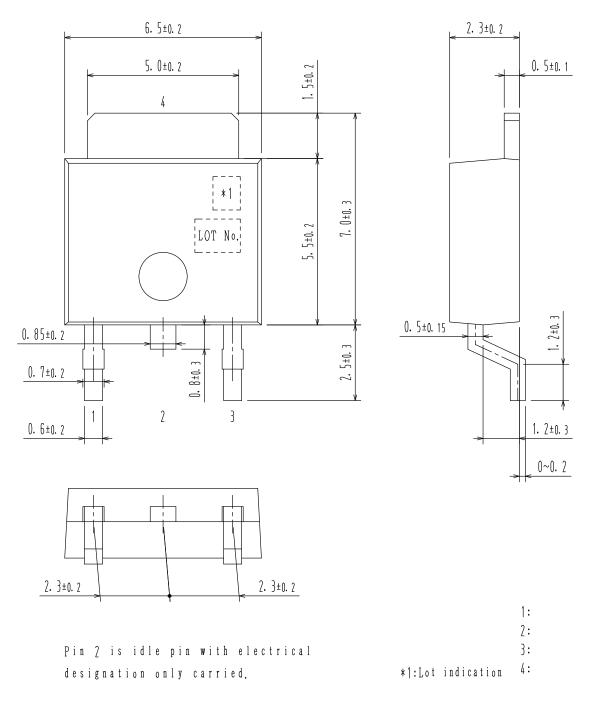
ORDERING INFORMATION

Device	Package	Shipping	memo
2SB1203S-E	TP	500pcs./bag	Pb Free
2SB1203S-H	TP	500pcs./bag	Pb Free and Halogen Free
2SB1203T-H	TP	500pcs./bag	Pb Free and Halogen Free
2SD1803S-E	TP	500pcs./bag	Pb Free
2SD1803S-H	TP	500pcs./bag	Pb Free and Halogen Free
2SD1803T-E	TP	500pcs./bag	Pb Free
2SD1803T-H	TP	500pcs./bag	Pb Free and Halogen Free
2SB1203S-TL-E	TP-FA	700pcs./bag	Pb Free
2SB1203S-TL-H	TP-FA	700pcs./bag	Pb Free and Halogen Free
2SB1203T-TL-E	TP-FA	700pcs./bag	Pb Free
2SB1203T-TL-H	TP-FA	700pcs./bag	Pb Free and Halogen Free
2SD1803S-TL-E	TP-FA	700pcs./bag	Pb Free
2SD1803S-TL-H	TP-FA	700pcs./bag	Pb Free and Halogen Free
2SD1803T-TL-E	TP-FA	700pcs./bag	Pb Free
2SD1803T-TL-H	TP-FA	700pcs./bag	Pb Free and Halogen Free



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DATE 30 JAN 2012

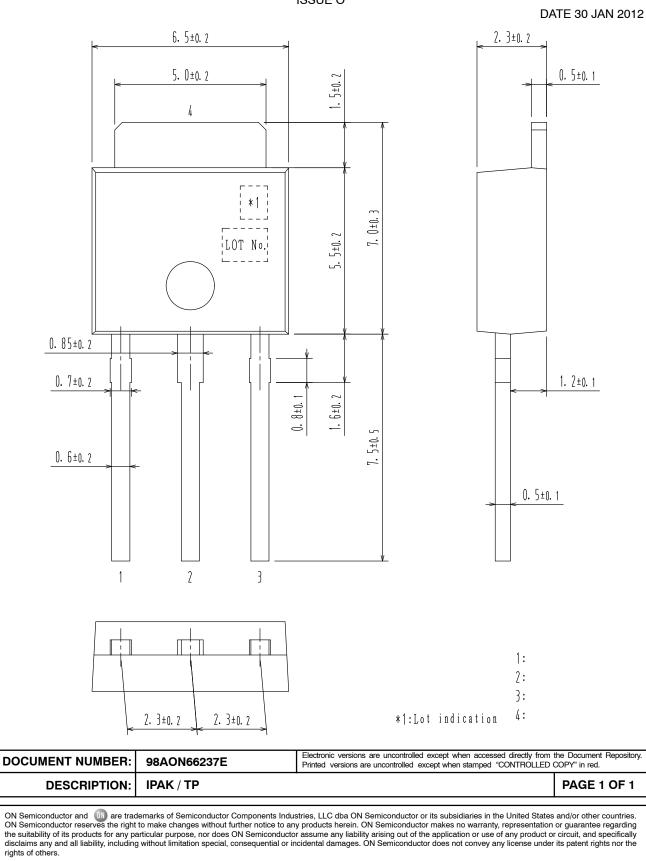


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